

**Trans IGBT Module N-CH 3300V 1.2KA 11mW 9-Pin
IHVB190-3 Tray**



Images are for reference only

[Inquiry](#)

Manufacturer: [Infineon Technologies Corporation](#)

Package/Case: MODULE

Product Type: Thyristors

Lifecycle: Unconfirmed

General Description

IHM B 3300 V, 1200 A 190 mm single switch IGBT Module with TRENCHSTOP™ IGBT3 and Emitter controlled 3 Diode. Also available in IHV-A package: FZ1200R33KF2C

Key Features

- High DC stability
- High short circuit capability
- Self limiting short circuit current
- Low switching losses
- Unbeatable robustness
- Tvj op = 150°C
- Low VCEsat with positive temperature coefficient
- AlSiC base plate for increased thermal cycling capability
- Package with CTI > 600
- Isolated base plate
- Standardized housing

Application

- Motor control and drives
- Wind energy systems
- Traction
- Commercial, construction and agricultural vehicles (CAV)

Recommended For You

IRFZ46NPBF

Infineon Technologies Corporation

TO-220

IRFZ44NPBF

Infineon Technologies Corporation

TO-220

FZ600R12KE4

Infineon Technologies Corporation

MODULE

IRFZ48NPBF

Infineon Technologies Corporation
TO-220

FZI800R16KF4

Infineon Technologies Corporation
MODULE

FZ2400R17HE4_B9

Infineon Technologies Corporation
MODULE

FZ600R12KP4

Infineon Technologies Corporation
MODULE

FZI800R12KF4

Infineon Technologies Corporation
MODULE

FZ400R12KS4

Infineon Technologies Corporation
IGBT

FZ750R65KE3

Infineon Technologies Corporation
MODULE

FZ3600R17HP4

Infineon Technologies Corporation
MODULE

IRFZ44VPBF

Infineon Technologies Corporation
TO-220

FZ1200R17HP4

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MODULE

FZI800R12KL4C

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MODULE

FZ1500R33HE3

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